

Preliminary

PJU110N06 / PJD110N06 / PJP110N06 / PJF110N06

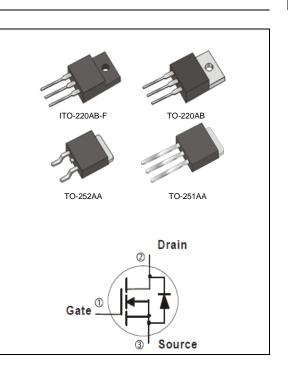
60V N-Channel Enhancement Mode MOSFET

60 V 110 A Voltage Current Features $R_{DS(ON)}, V_{GS}@10V, I_D@20A < 8m\Omega$ • High switching speed • Improved dv/dt capability • Low reverse transfer capacitance • Lead free in compliance with EU RoHS 2011/65/EU directive. • Green molding compound as per IEC61249 Std. (Halogen Free) **Mechanical Data** • Case : TO-251AA, TO-252AA, TO-220AB, ITO-220AB-F Package • Terminals : Solderable per MIL-STD-750, Method 2026

- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 1.9 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams

Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	ITO-220AB-F	TO-252AA	UNITS
Drain-Source Voltage		V _{DS}	60				V
Gate-Source Voltage		V_{GS}	<u>+</u> 25				V
Continuous Drain Current	T _C =25°C	I _D	110				
	$T_{C}=100^{\circ}C$		81				А
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	440				
Power Dissipation	T _C =25°C	PD	214	250	88	214	W
	T _C =100°C		107	125	44	107	
Continuous Drain Current	T _A =25°C	l _D	11.2				A
	T _A =70°C		9.4				
Power Dissipation	T _A =25°C		2.5	2.0	1.0	2.5	14/
Power Dissipation	T _A =70°C	Pd	1.6	1.3	0.7	1.6	W
Single Pulse Avalanche Energy (Note 6)		E _{AS}	101				mJ
Operating Junction and		T _J ,T _{STG}	-55~150				°C
Storage Temperature Range							
Typical Thermal resistance ^(Note 4,5)							
- Junction to Case		$R_{ extsf{ heta}JC}$	1.5	1.25	3.5	1.5	°C/W
- Junction to Ambient		$R_{ extsf{ heta}JA}$	50	62.5	120	50	





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Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2	3	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =20A	-	6.5	8	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =48V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 25V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V _{DS} =30V, I _D =30A, V _{GS} =10V ^(Note 2,3)	-	70	-	nC
Gate-Source Charge	Q _{gs}		-	16	-	
Gate-Drain Charge	Q _{gd}		-	24	-	
Input Capacitance	Ciss	V_{DS} =25V, V_{GS} =0V,	-	3580	-	pF ns
Output Capacitance	Coss		-	360	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	245	-	
Turn-On Delay Time	td _(on)		-	16	-	
Turn-On Rise Time	tr	V_{DS} =30V,I _D =30A,	-	118	-	
Turn-Off Delay Time	td _(off)	V _{GS} =10V, R _G =6.8Ω (Note 2,3)	-	52	-	
Turn-Off Fall Time	t _f		-	62	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	110	А
Diode Forward Current	I _S					
Diode Forward Voltage	V_{SD}	I _S =20A,V _{GS} =0V	-	-	1.3	V

NOTES :

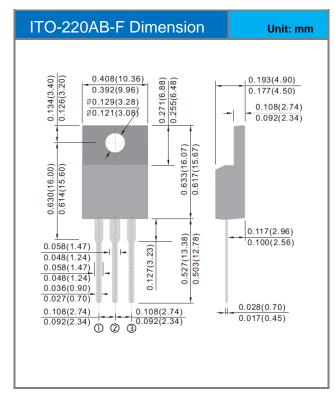
- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS}=45A, V_{DD}=25V, V_{GS}=10V, R_G=25ohm, Starting T_J=25^{\circ}C
- 7. Guaranteed by design, not subject to production testing.

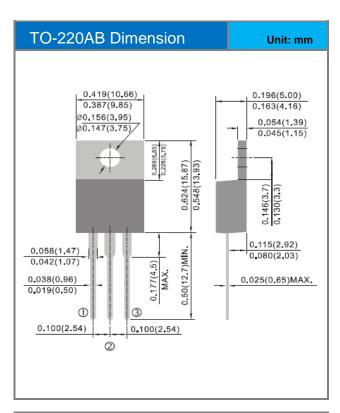


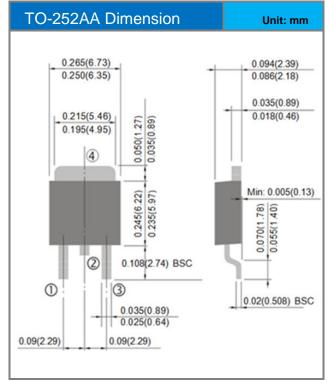
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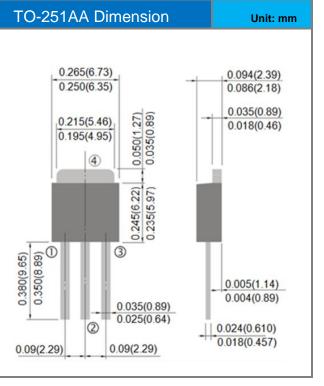
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Packaging Information









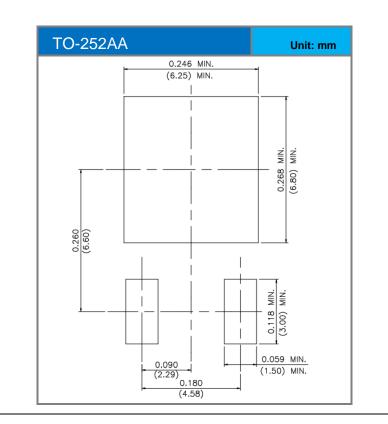


PJU110N06 / PJD110N06 / PJP110N06 / PJF110N06

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJD110N06_L2_00001	TO-252AA	3,000pcs / 13" reel	D110N06	Halogen free
PJU110N06_T0_00001	TO-251AA	80pcs / Tube	U110N06	Halogen free
PJP110N06_T0_00001	TO-220AB	50pcs / Tube	P110N06	Halogen free
PJF110N06_T0_00001	ITO-220AB-F	50pcs / Tube	F110N06	Halogen free

MOUNTING PAD LAYOUT





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